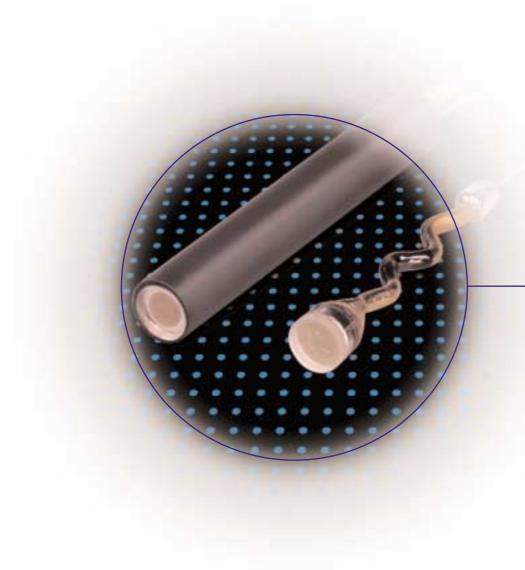


# **Channel Photomultipliers Overview and Specifications**





#### CHANNEL PHOTOMULTIPLIER







#### **Features**

- Ultra high anode sensitivity up to 10<sup>7</sup> A/W
- Extremely low dark current, typically 3pA @ 10<sup>6</sup> gain
- Very low equivalent noise input (down to 10<sup>-17</sup> W)
- Very high stability in dark current (no "bursts")
- High gain exceeding 10<sup>8</sup>
- Very high dynamic range
- Compact dimensions
- Wide spectral response through multiple window materials
- High resolution
- Fast response time
- High immunity to magnetic fields
- Rugged design

#### **Description**

PerkinElmer Optoelectronics, formerly EG&G Optoelectronics, is pleased to introduce the Channel Photomultiplier (CPM), a new ultra high sensitivity optical detector which replaces conventional photomultipliers (PMTs) and avalanche photo diodes (APDs). This device uses a unique detector principle, resulting in a compact design with ultra high gain, high dynamic range, extremely low dark current, and fast response.

This high-performance detector offers fundamental advantages for analytical instrumentation applications such as emission spectroscopy, flourescence, atomic absorption spectroscopy, and bio and chemo luminescence. The CPM also delivers important advantages in life science products, industrial and medical equipment, and highenergy physics.

When compared to conventional PMTs, the CPM improves anode sensitivity by one order of magnitude, while lowering dark current by one to two orders of magnitude. The noise level shows extreme stability over time, with no "bursts." The extremely low dark current results in a higher dynamic range than conventional PMTs and extends detectable limits for many applications.

The CPM can be used in analog-DC mode, single photon counting mode, and in nuclear spectroscopy (when coupled to scintillation materials like BGO, LSO, Nal, etc.). PerkinElmer Optoelectronics offers a choice of window materials and photocathodes to cover the spectrum from 115 nm (UV range) to 900 nm (NIR).

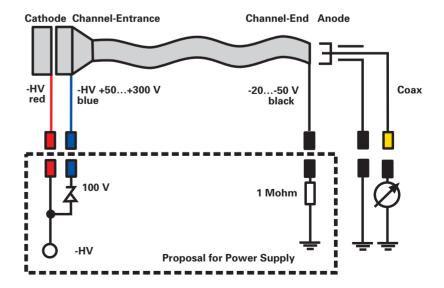
The new detector is a small, head-on type with a total diameter of 10.5 mm including encapsulation. PerkinElmer Optoelectronics also offers custom configurations for specific applications.

#### PRINCIPLE OF OPERATION

#### **Principle of Operation**

The CPM, like conventional photomultiplier tubes, converts a very low light level into photoelectrons by a semitransparent photocathode deposited on the inner surface of the entrance window. On their way from the cathode to the anode the photoelectrons pass through a narrow, semiconductive channel. Each time the electrons hit the inner wall of the curved channel, multiple secondary electrons are emitted. This effect occurs multiple times along the path, leading to an avalanche effect with a gain exceeding 108. The curved shape of the glass tube improves the multiplication effect.

#### **Physical Specification**

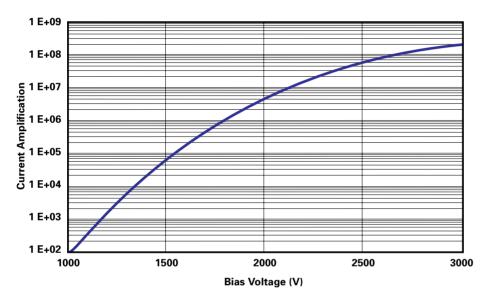


#### MAIN FEATURES



Unpotted 1/3 inch Channel Photomultiplier

Fig. 1: Typical current amplification



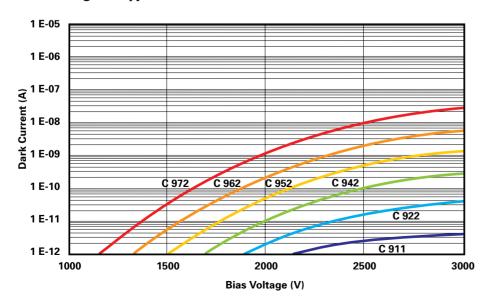
#### **Compact Size**

The CPM is one of the smallest headon type detectors, with a 10.5 mm diameter including encapsulation. The photocathode has a useful diameter of more than 5 mm. The tube is smaller, easier to use, and more rugged than discrete dynode types. Only a single high voltage supply of up to 3000 volts is necessary; no external voltage divider network is required. A variety of different sizes will be available soon (1/2" and 3/4").

#### Ultra high anode sensitivity

At the maximum bias voltage of 3000 V, gains can exceed 10°. At 2400 V, anode sensitivity is typically 3 x 10° AWV at a wavelength of 410 nm with a bialkali photocathode. This performance surpasses conventional PMTs by one to two orders of magnitude and beats APDs by approximately five orders of magnitude (Fig. 1).





#### **Extremely low dark current**

The electron multiplication in the channel is virtually silent, so dark current depends only on the photocathode material, leakage currents are negligible. Bialkali photocathodes exhibit typical dark count rates of 10 cps at a gain of 3 x 108, while UV cathodes have dark count rates below 1 cps. In analog DC mode, the typical dark noise for a bialkali photocathode is 20 pA at a gain of 107. In general, the noise level of the PerkinElmer Optoelectronics CPM is one to two orders of magnitude lower than dynode PMTs, resulting in a significantly higher dynamic range (Fig.2).

#### High stability in dark current level

As a result of the semiconductive inner surface of the CPM, no charge-up effects occur at the glass surface. This results in a very high stability of the dark current level over time, with no sudden changes (bursts). The semiconductive surface also causes high-light recovery times to be extremely small.

Fig. 3: Typical photo electron spectrum

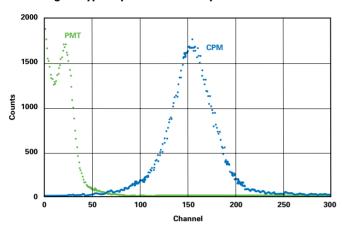


Fig. 4.1: Typical spectral response

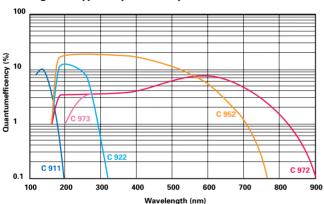
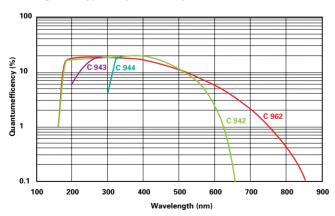


Fig. 4.2: Typical spectral response



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#### **Excellent photon counting resolution**

At gains exceeding 10<sup>7</sup> the single photo electron pulse is perfectly separated from the electrical noise, due to a saturation effect of the channel. The CPM exhibits single photon resolution with excellent peak to valley ratios. Fig. 3 shows the single photo electron spectrum taken from a multi-channel analyzer compared to a conventional photomultiplier (Fig. 3).

#### Choice of entrance window

The CPM is available with different window materials, which are:

MgF<sub>2</sub>, Quartz, UV-glass, and Borosilicate glass. The combination of different photocathodes and entrance windows results in a spectral range from 115 nm to 900 nm. Other window materials and photocathode combinations are available on a custom basis (Fig. 4.1 and 4.2).

#### **Available related products**

#### • High Voltage supply

CHV 30N (supplies 1 CPM, negative output voltage), CHV 30P (supplies 1 CPM, positive output voltage), J4-3N (supplies 10 to 15 CPMs)

#### CPM Modules

MP900-series: Photoncounting module with

TTL output, including CPM, electronic and high voltage

MD900-series: DC module including high

voltage supply, amplifier, I/U converter, output 0 to 10 V,

bandwidth 1kHz

MH900-series: High voltage module,

including CPM and

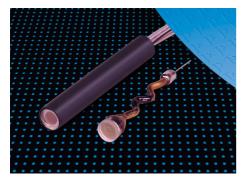
high voltage power supply

#### CPM Formats

1/<sub>3</sub>" C900-series 1/<sub>2</sub>" C1300-series 3/<sub>4</sub>" C1900-series

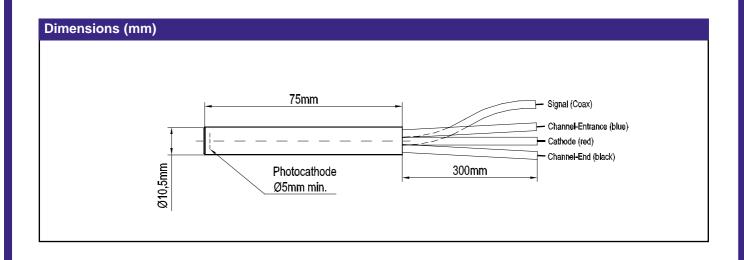
#### Datasheets on request

## **CPM C900 Series** 1/3" **CPM Channel Photomultipliers**



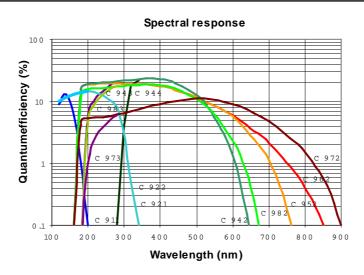
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/3 Inch, Head-On Type

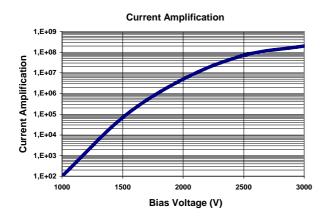
Tec	Technical Specifications																								
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	@ 560 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)		
C911	115-200	Csl		MgF <sub>2</sub>				6x10 <sup>5</sup>				2	1x10 <sup>-17</sup>					C911P			0.1				
C921	115-320	CsTe		MgF <sub>2</sub>					x10 <sup>6</sup>			10	1x10 <sup>-17</sup>					C921P			1				
C922	165-320	CsTe		Quartz				1	x10 <sup>6</sup>			10	1x10 <sup>-17</sup>					C922P			1				
C942	165-650	Bial kali		Quartz				-				3x10 <sup>6</sup>		80	1x10 <sup>-17</sup>		뉟			C942P			10		
C943	185-650	3ia		UV glass							3x10 <sup>6</sup>	_	80	1x10 <sup>-17</sup>		nrre			C943P			10			
C944	300-650			Borosil.	plier					_		3x10 <sup>6</sup>		80	1x10 <sup>-17</sup>		as c	sec.)		C944P	1		10		
C952	165-750	nois iialk		Quartz	lulti	00						3x10 <sup>6</sup>		250	2.5x10 <sup>-17</sup>	17	fbië			C952P			40		
C953	185-750	Low noise Multialk.	2	UV glass	tron N	(max. 3000)				3x10 <sup>6</sup>		250	2.5x10 <sup>-17</sup>	0	50 limit) 10% of bias current	10 µA (max. 30 s		C953P	(max. 3000)	3x10 <sup>8</sup>	40	10:1	50		
C962	165-850	Multialk.	,	Quartz	Channel Electron Multiplier					2:	к10 <sup>6</sup>	1000	4x10 <sup>-17</sup>	5			., 0	C962P			100	10	5		
C963	185-850	Mu		UV glass	anne	2400				2:	к10 <sup>6</sup>	1000	4x10 <sup>-17</sup>		arity	10 µ		C963P	3000 (n		100				
C972	165-900	Extend. red Multialk.		Quartz	ි පි					2:	x10 <sup>6</sup>	5000	1.5x10 <sup>-16</sup>		(DC linearity limit)			C972P	30		500				
C973	185-900	Mul z		UV glass						2:	к10 <sup>6</sup>	5000	1.5x10 <sup>-16</sup>		0			C973P			500				
C982	165-650	¥ se ≼		Quartz									3x10 <sup>6</sup>		25	6x10 <sup>-18</sup>					C982P			3	
C983	185-650	Low noise Bialk.		UV glass						3x10 <sup>6</sup>		25	6x10 <sup>-18</sup>					C983P			3				

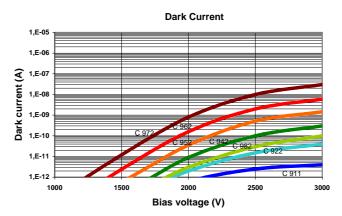


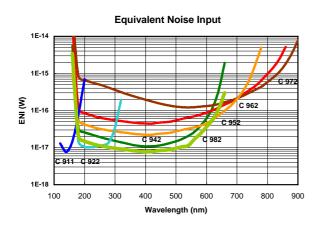
## CPM C900 Series 1/3" CPM Channel Photomultipliers

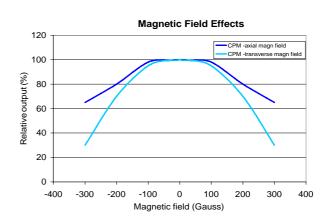
#### **CPM C900 Performance Specifications**









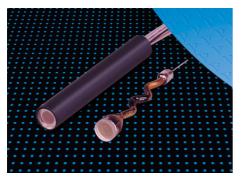


#### **CAUTION: High Voltage Warning!**

This product is operated at high voltage. Extreme care must be taken to ensure operator safety and to avoid damage to other instruments. Avoid direct contact with the photomultiplier when high voltage is applied. Avoid placing conductive material close to the cathode.

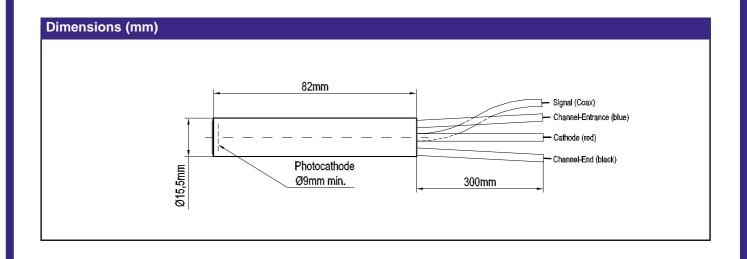
All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.

## **CPM C1300 Series** 1/2" **CPM Channel Photomultipliers**



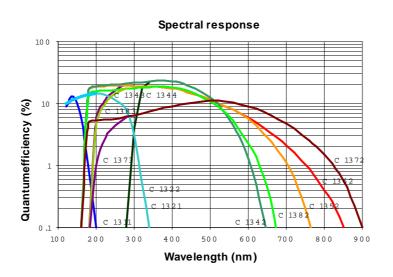
- High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 1/2 Inch, Head-On Type

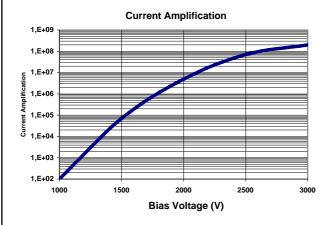
Techr	nical Sp	ecifica	atio	ons																											
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 560 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)									
0.011	115.000	0.1						0.405				0.40:17					040445					$\perp$									
C1311	115-200	Csl		MgF <sub>2</sub>				6x10 <sup>5</sup>	4.0fi		8	2x10 <sup>-17</sup>					C1311P			0.4											
C1321	115-320	CsTe		MgF <sub>2</sub>					10 <sup>6</sup>		40 40	2x10 <sup>-17</sup> 2x10 <sup>-17</sup>					C1321P			4											
C1322 C1342	165-320 165-650	CsTe :=		Quartz Quartz				ı x	3x10	6	320	2x10 2x10					C1322P C1342P			40											
C1342	185-650	Bial kali		UV glass					3x10		320	2x10 <sup>-17</sup>	1	ent			C1342P			40											
C1344	300-650	Bia		Borosil.						3x10		320	2x10 <sup>-17</sup>		curr			C1344P			40										
C1352	165-750	Low noise Multialk.		Quartz		3000)			3x10		1000	4x10 <sup>-17</sup>		(DC linearity limit) 10% of bias current	sec.)		C1352P			160											
C1353	185-750	Low		UV glass				0,	0,	0,	0,	0,	0,	0,	0,	0,	0,		3x10	6	1000	4x10 <sup>-17</sup>		%0	. 30		C1353P	3000	08	160	-
C1362	165-850	Multialk.	6	Quartz		2400 (max.	5x10 <sup>7</sup>		2	2x10 <sup>6</sup>	4000	8x10 <sup>-17</sup>	50	Julimit) 1 A (may	10 µA (max. 30 sec.)	9	C1362P	(max. 3	3x10 <sup>8</sup>	400	10:1	90									
C1363	185-850	Mu		UV glass		240			2	2x10 <sup>6</sup>	4000	8x10 <sup>-17</sup>		arity	10 µ		C1363P	00		400											
C1372	165-900	Extend. red Multialk.		Quartz					2	2x10 <sup>6</sup>	20000	3x10 <sup>-16</sup>		C line			C1372P	3000		2000											
C1373	185-900			UV glass					2	2x10 <sup>6</sup>	20000	3x10 <sup>-16</sup>		긔			C1373P			2000											
C1382	165-650			Quartz					3x10	6	100	1x10 <sup>-17</sup>					C1382P			10											
C1383	185-650	Low noise Bialk.		UV glass					3x10	6	100	1x10 <sup>-17</sup>					C1383P			10											

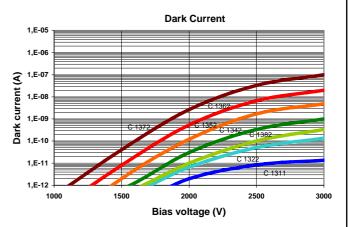


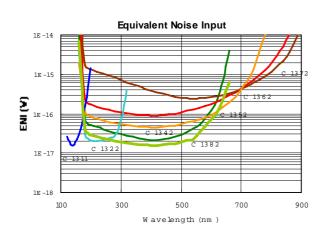
## **CPM C1300 Series**1/2" **CPM Channel Photomultipliers**

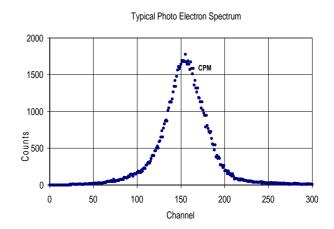










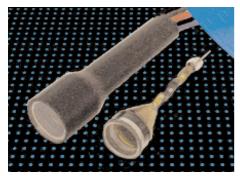


#### **CAUTION: High Voltage Warning!**

This product is operated at high voltage. Extreme care must be taken to ensure operator safety and to avoid damage to other instruments. Avoid direct contact with the photomultiplier when high voltage is applied. Avoid placing conductive material close to the cathode.

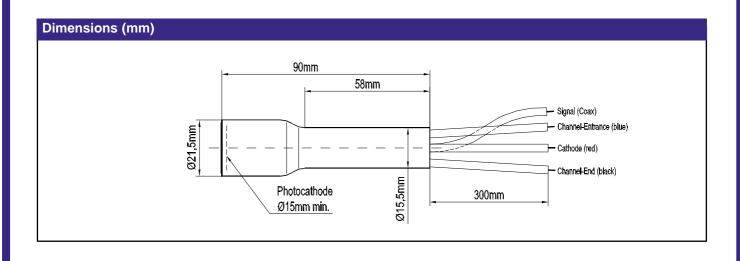
All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.

## **CPM C1900 Series** 3/4" **CPM Channel Photomultipliers**



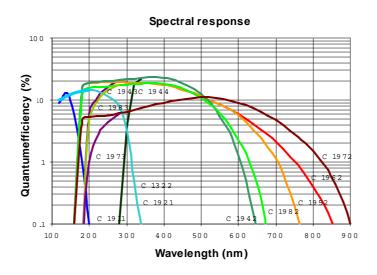
- · High Sensitivity Optical Detector
- · Extremely High Gain
- · Ultra Low Noise
- · 3/4 Inch, Head-On Type

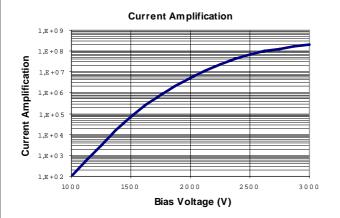
Techi	nical Sp	ecifica	atio	ons																															
Туре	Spectral response (nm)	Photocathode material	Min. useful area (mm)	Window material	Electron multiplication	Supply voltage (V)	Current amplification	@ 140 nm (A/W)	@ 200 nm (A/W)	@ 400 nm (A/W)	Dark current (pA)	Equivalent Noise Input, ENI (W)	Bias current (µA)	Max. linear anode current	Max. anode current*	Response time Rise time (ns) Pulse width / FWHM (ns)	Special types for Photon Counting	Supply voltage (V)	Single photo electron gain	Dark counts (cps)	Peak to valley	Max. ambient temperature (°C)													
								-				47																							
C1911	115-200	Csl		MgF <sub>2</sub>				6x10 <sup>5</sup>			20	3x10 <sup>-17</sup>					C1911P			1															
C1921	115-320	CsTe		MgF <sub>2</sub>			5×107		x10 <sup>6</sup>		100	3x10 <sup>-17</sup>					C1921P			10															
C1922	165-320	CsTe		Quartz				1>	x10 <sup>6</sup>	.40 <sup>6</sup>	100	3x10 <sup>-17</sup>					C1922P			10															
C1942	165-650	Bial kali		Quartz	+			5x10 <sup>7</sup>	5×10 <sup>7</sup>	5x10 <sup>7</sup>			(10 <sup>6</sup>	800	3x10 <sup>-17</sup>		ij			C1942P	-		100												
C1943	185-650	Bial		UV glass	L						5x10 <sup>7</sup>	5x10 <sup>7</sup>	5x10 <sup>7</sup>	5x10 <sup>7</sup>	5x10 <sup>7</sup>	5x10 <sup>7</sup>			(10 <sup>6</sup>	800	3x10 <sup>-17</sup>		current			C1943P			100						
C1944	300-650			Borosil.	plie												5x10 <sup>7</sup>	5x10 <sup>7</sup>		3x10 <sup>6</sup>		800	3X10		as c	_		C1944P	-		100				
C1952	165-750	nois tialk		Quartz	1ulti	00													5×10 <sup>7</sup>	5x10 <sup>7</sup>	3		ر10 <sup>6</sup>	2500	8x10 <sup>-17</sup>		f bi	sec.)		C1952P	,		400		
C1953	185-750	Low noise Multialk.	3	UV glass	ron N	1X. 30																3x10 <sup>6</sup> 2500 8x10 <sup>-17</sup> 0 6 8 C1953F	C1953P	3000)	90	400	<del></del>								
C1962	165-850	ak.	13	Quartz	Elect	2400 (max. 3000)																	2x10 <sup>6</sup>	10000	1x10 <sup>-16</sup>	50	mit) 1	μΑ (max.	6 3			3x10 <sup>8</sup>	1000	10:1	20
C1963	185-850	Multialk.		UV glass	Channel Electron Multiplier	2400				2x10 <sup>t</sup>	10000	1x10 <sup>-16</sup>		arity li	10 µA		C1963P	3000 (max.		1000															
C1972	165-900	and. d ialk.		Quartz	S					2x10 <sup>t</sup>	50000	5x10 <sup>-16</sup>		(DC linearity limit) 10% of bias			C1972P	300		5000															
C1973	185-900	Extend. red Multialk.		UV glass							2x10		5x10 <sup>-16</sup>		(DC			C1973P			5000														
C1982	165-650	se K.		Quartz										3×	(10 <sup>6</sup>	250				25															
C1983	185-650	Low noise Bialk.		UV glass					3×	د10 <sup>6</sup>	250	2x10 <sup>-17</sup>					C1983P			25															

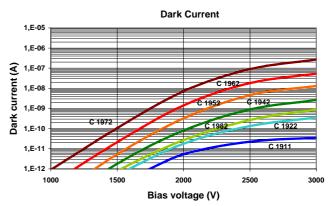


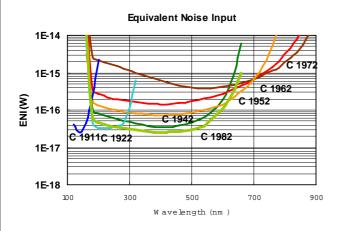
## **CPM C1900 Series** 3/4" **CPM Channel Photomultipliers**

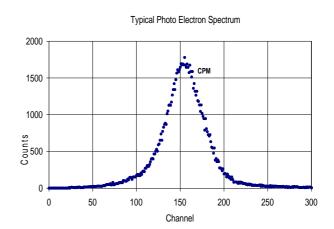
#### **CPM C1900 Performance Specifications**











#### **CAUTION: High Voltage Warning!**

This product is operated at high voltage. Extreme care must be taken to ensure operator safety and to avoid damage to other instruments. Avoid direct contact with the photomultiplier when high voltage is applied. Avoid placing conductive material close to the cathode.

All given values are nominal/typical @ 20 °C ambient temperature; specifications subject to change without notice.



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